

### **INCHANGE SEMICONDUCTOR**

# isc N-Channel MOSFET Transistor

### DMT6009LCT

#### **FEATURES**

- Drain Current –I<sub>D</sub>= 37.2A@ T<sub>C</sub>=25℃
- · Drain Source Voltage-: V<sub>DSS</sub>= 60V(Min)
- Static Drain-Source On-Resistance
- :  $R_{DS(on)} = 12m \Omega$  (Max)
- 100% avalanche tested
- Minimum Lot-to-Lot variations for robust device performance and reliable operation

#### DESCRIPTION

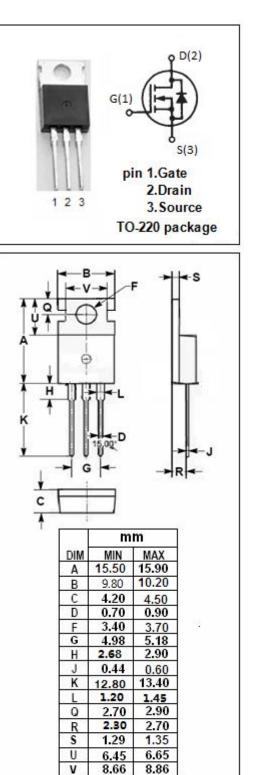
• Designed for use in switch mode power supplies and general purpose applications.

ABSOLUTE MAXIMUM RATINGS(Ta=25 C)						
SYMBOL	PARAMETER	VALUE	UNIT			
V <sub>DSS</sub>	Drain-Source Voltage	60	V			
V <sub>GS</sub>	Gate-Source Voltage-Continuous	±16	V			
ID	Drain Current-Continuous	37.2	A			
I <sub>DM</sub>	Drain Current-Single Pluse	80	A			
P <sub>D</sub>	Total Dissipation @Tc=25°C 25		w			
TJ	Max. Operating Junction Temperature -55~150		°C			
T <sub>stg</sub>	Storage Temperature	-55~150	°C			

### ABSOLUTE MAXIMUM PATINGS(T=25°C)

### **THERMAL CHARACTERISTICS**

SYMBOL	PARAMETER	МАХ	UNIT
R <sub>th j-c</sub>	Thermal Resistance, Junction to Case	5.0	°C/W



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#### **ELECTRICAL CHARACTERISTICS**

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SYMBOL	PARAMETER	CONDITIONS	MIN	МАХ	UNIT
V <sub>(BR)DSS</sub>	Drain-Source Breakdown Voltage	V <sub>GS</sub> = 0; I <sub>D</sub> = 0.25mA	60		V
V <sub>GS(th)</sub>	Gate Threshold Voltage	$V_{DS}$ = $V_{GS}$ ; $I_D$ = 0.25mA	0.7	2.0	V
R <sub>DS(on)</sub>	Drain-Source On-Resistance	V <sub>GS</sub> = 10V; I <sub>D</sub> = 13.5A		12	mΩ
lgss	Gate-Body Leakage Current	V <sub>GS</sub> = ±16V;V <sub>DS</sub> = 0		±100	nA
IDSS	Zero Gate Voltage Drain Current	V <sub>DS</sub> = 48V; V <sub>GS</sub> = 0		1.0	μA
V <sub>SD</sub>	Forward On-Voltage	I <sub>S</sub> = 20A; V <sub>GS</sub> = 0		1.2	V

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